Lecture 4

Conductance sensors. ChemFET.

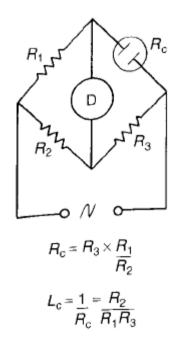
Electrochemical Impedance Spectroscopy. Practical consideration for electrochemical biosensors.

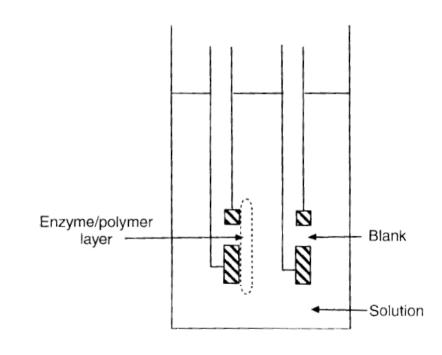
Conductivity

$$V = I \times R = \frac{I}{L}$$
, L - conductance

$$L = \kappa A/l, \quad \Lambda = \kappa/[C]$$

- Directly proportional to the concentration of ions in the solution
- Depends on charge, mobility and degree of dissocation of ions
- Any reaction that produces change in a number of ions or in the charge of ions can be monitored.
- No selectivity in itself

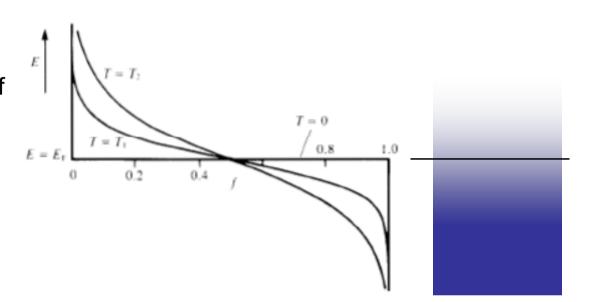




Electrode: solid metal

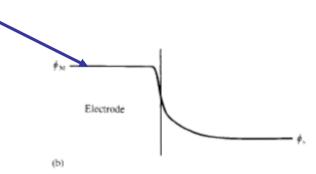
• Fermi distribution only electrones within kT of Ef can be transferred

$$f = 1/(1 + \exp(E - E_F)/kT)$$



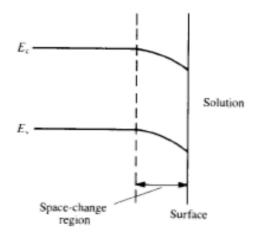
High electron density

Additional effect related to crystallographic orientation, reorganisation of metal surface during potential cycling etc.



Semiconductor electrode (intrinsic semiconductor)

- Band gap
- E_f in the middle of the gap
- Number of excited electrons ~exp(-E_q/2kT)
- Lower density of state, space-charge region is large and therefore most of potential variation occurs there (Cd~10-100uF, Csc<1uF)



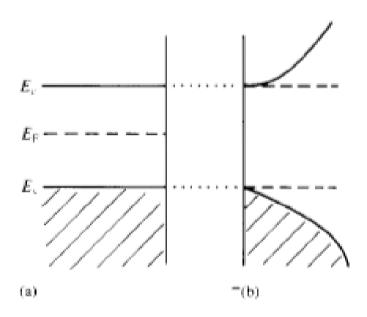


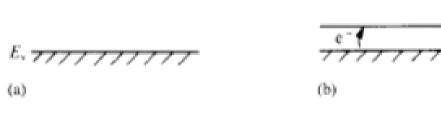
Table 3.1. Bandgap energy, E_g , and corresponding wavelength λ_{bg} (important for photo-excitation) of some semiconductors of electrochemical interest²⁵. Zone of visible light (300 \rightarrow 950 nm)

Semiconductor	E_z/eV	$\lambda_{\rm bg}/{\rm nm}$
SnO ₂	3.5	350
ZnO	3.2	390
rTiO ₃	3.2	390
ΓiO ₂	3.0	410
CdS	2.4	520
6aP	2.3	540
e ₂ O ₃	2.1	590
dSe	1.7	730
dTe	1.4	890
aAs	1.4	890
P	1.3	950
i	1.1	1130

Doped semiconductors



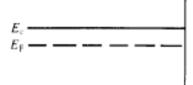
Empty



N-type P-type

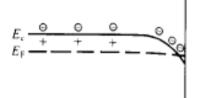
Types of space charge region in n-type semiconductor

Flat-band potential





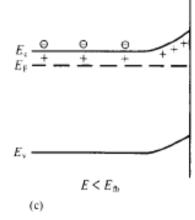
$$E=E_{\rm fb} \label{eq:energy}$$
 (a)

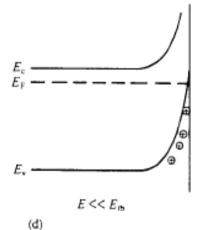


(b)

Accumulation layer

Depletion layer





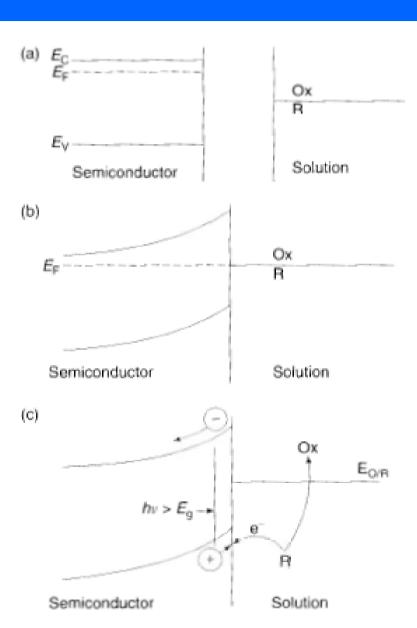
Inversion

Semiconductor-solution contact

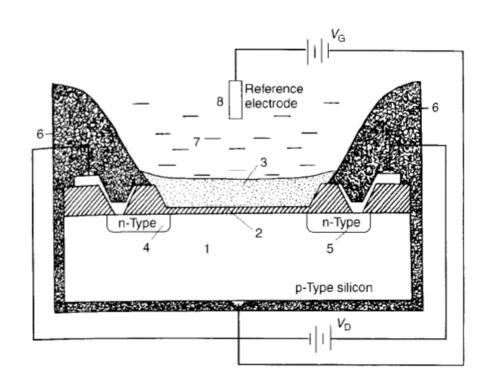
semiconductor and liquid separated:

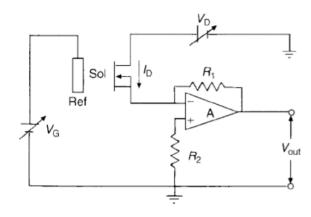
 equilibrium in the dark: Fermi level is aligned to E⁰.

photocatalysis

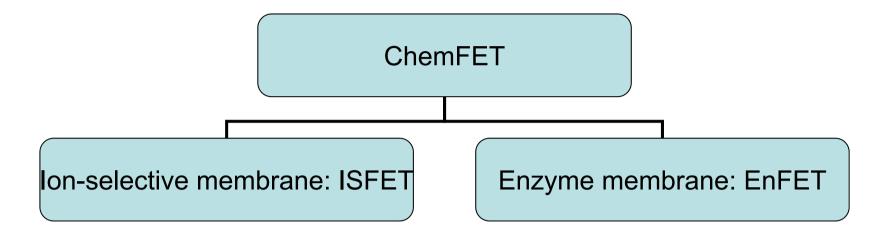


ChemFET: Chemically sensitive FET





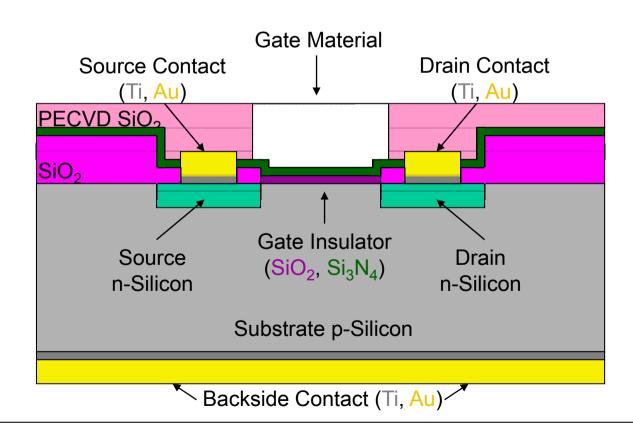
ChemFET: Chemically sensitive FET



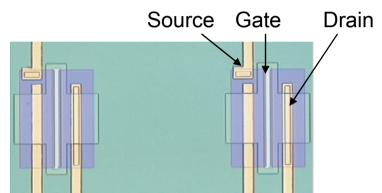
- Membranes with mobile ionexchanger
- Membranes containing neutral ionophores
- Membranes with fixed ionic sites

• based on interaction of enzyme with analyte, extremely selective

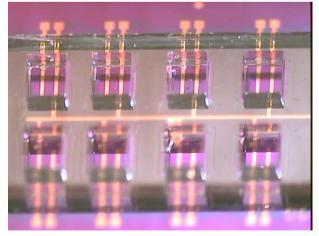
ChemFET fabrication



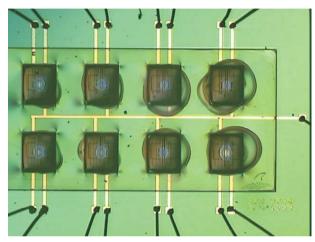
Process Snapshots



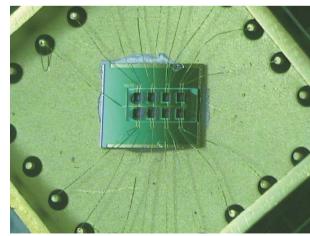
Working Area Lithography



Epoxy Well Definition



Conducting Polymer Deposition

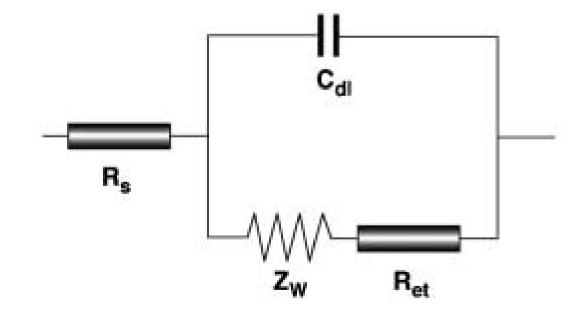


Wire bonded to Header

- Reactions on the surface (e.g. formation of a recognition complex) will lead to change of capacitance and resistance of electrode-solution interface
- Impedance is a complex resistance encountered when current flows through a circuit containing resistors, capacitors and inductors

Randles and Ersher equivalent circuit model

- C_{dl} double layer capacitance
- R_{et} electron transfer resistance
- R_s Ohmic resistance of the solution
- Z_w Warburg impedance due to diffusion of ions from bulk to the surface



• From the circuit theory: impedance of basic electric

elements:

$$v(t) = L \frac{di}{dt}$$

$$+ L \qquad \Rightarrow \qquad V = j\omega LI$$

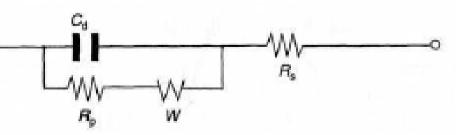
$$+ L \qquad \Rightarrow \qquad I$$

$$i(t) = Re\{Ie^{j\omega t}\}$$

$$\downarrow V = \frac{1}{j\omega C}I$$

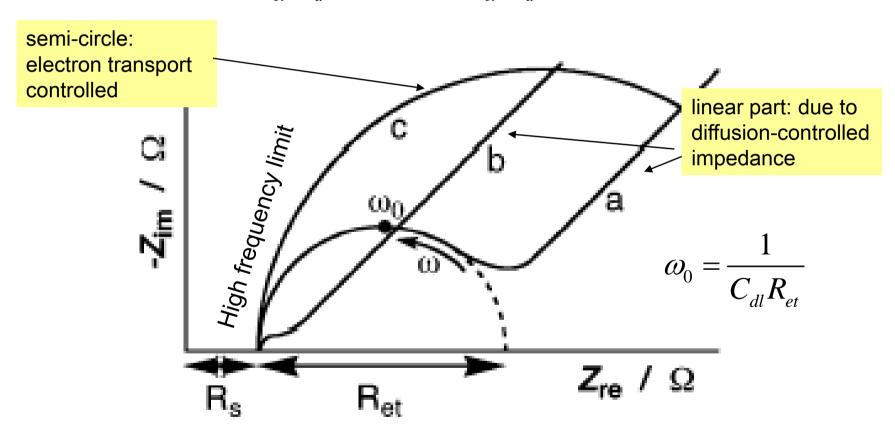
$$\downarrow V$$

So, we can calculate the impedance of our circuit...



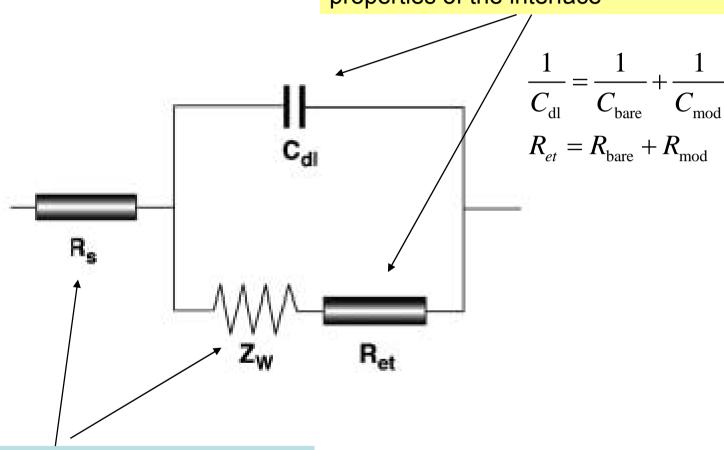
The impedance can written as:

$$Z(\omega) = R_s + \frac{R_{et}}{1 + \omega^2 R_{et}^2 C_d^2} - j\omega \frac{R_{et}^2 C_d}{1 + \omega^2 R_{et}^2 C_d^2} = Z' + jZ''$$



 Typical frequency range: 10mHz – 100 kHz (limited by the wires and e/chem cell)

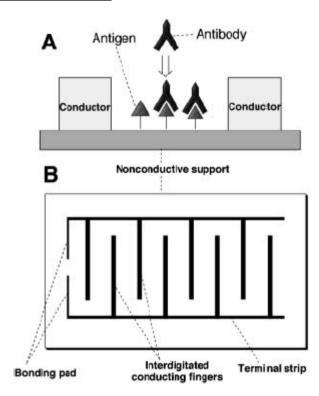
Depend on dielectric and conductive properties of the interface



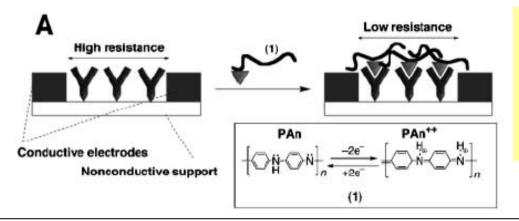
Represent bulk properties of the solution, not affected by the reactions at the interface

In-plane impedance measurements

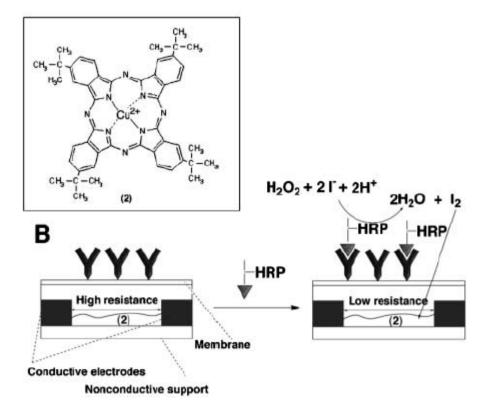
- Affinity binding in the gap results in the change of the electrical properties affecting the impedance between the electrodes:
- main contribution: capacitive changes due to change in dielectric constant
- Variations:
 - labelling IgG with bubble generating enzyme (e.g. catalase) to increase the change in dielectric constant
 - labelling IgG with conductive polymer chains
 - discontinuous metallic film in the gap



Examples



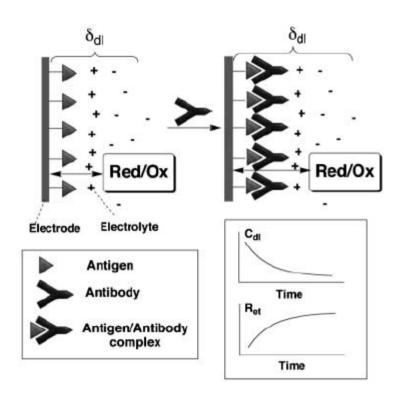
Increase in conductivity upon binding of polyaniline labelled IgG



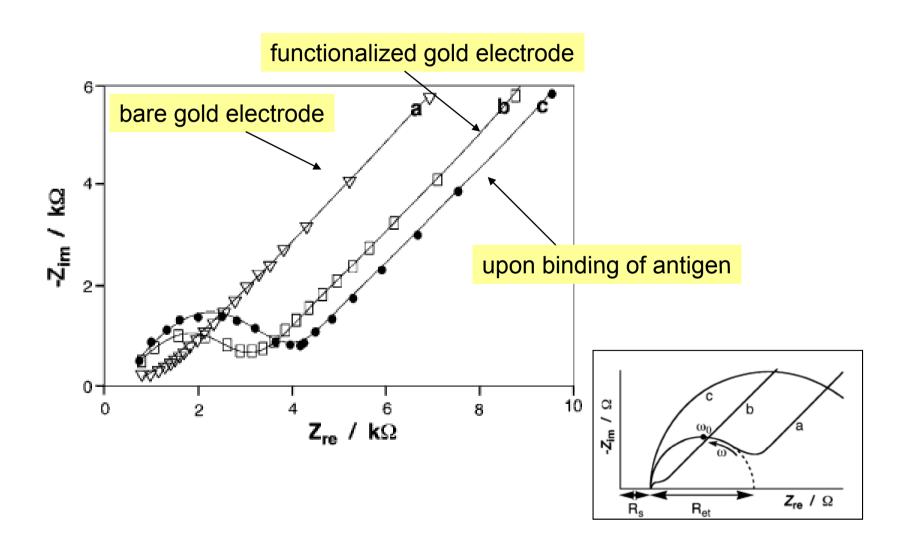
Increase in conductivity of copper phtalocyanine upon I₂ doping

Interfacial impedance measurements

- Formation of antigenantibody complex results in:
 - increase of the double-layer thickness
 - insulation of the electrode surface in respect to redox couple added to the solution

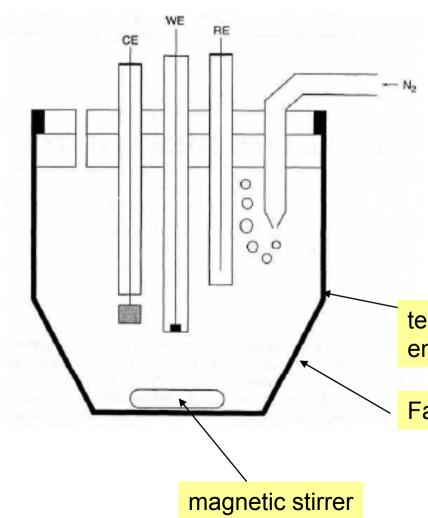


• Example: sensor for foot-and-mouth disease using faradeic spectroscopy (with 2mM Fe(CN)₆)^{-3/-4})



Practical considerations

Electrochemical cell for voltammetry



gas purging: oxygen removal is essential for many experiments as oxygen and its products can affect the process in question

$$O_2 + 2H^+ + 2e \rightarrow H_2O_2$$
 -0.1V vs SCE
 $H_2O_2 + 2H + 2e \rightarrow 2H_2O$ -0.9V vs SCE

temperature controlled environment

Faraday cage



Instrumentation

 Fully automated system for voltammetry measurements

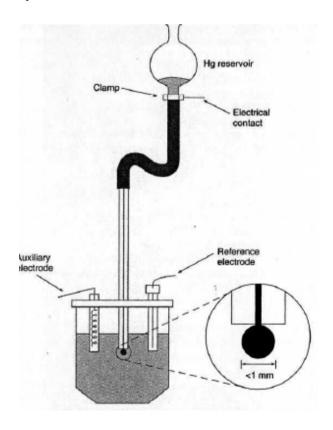


 Research grade system with capability for multiple techniques

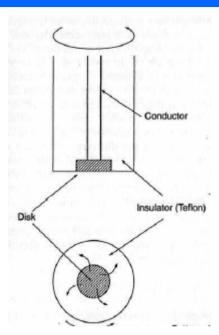


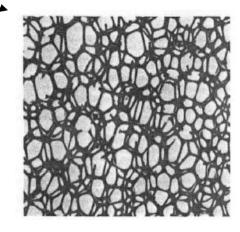


• Dropping mercury electrode (DME)

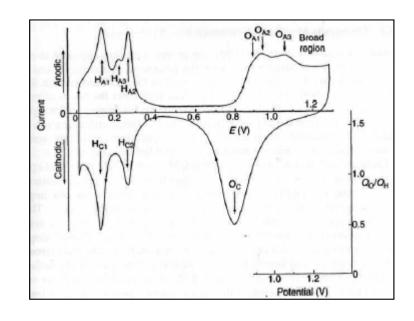


- Solid electrodes:
 - stationary (usually cylindrical rod in an insulating sleeve)
 - rotating
- Material for solid electrodes:
 - carbon
 - glassy carbon: wide potential window, chemically inert, can be made porous
 - carbon paste electrode: graphite powder+ organic binder
 - diamond electrodes (boron-doped): low double layer capacitance (due to absence of C-O bonds), extreme hardness
 - metal electrodes: good electron transfer kinteics





- Material for solid electrodes:
 - metal electrodes made of noble metals:
 - good electron transfer kinetics
 - large anodic window
 - small cathodic window due to low hydrogen overvoltage (-0.2 — -0.5V depending on pH)
 - high background currents associate with formation of surface oxide and hydrogen layers
 - other metals can be used depending on application (Cu, Ni, Ag, Pt-Ru etc.)



Pt oxide formation and reduction in 0.5M H₂SO₄.

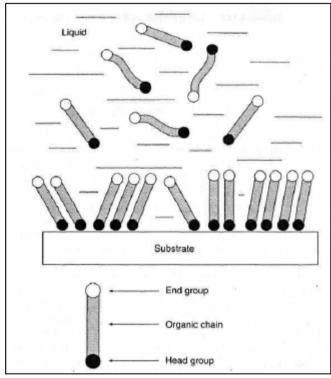
Chemically modified electrodes: properties of

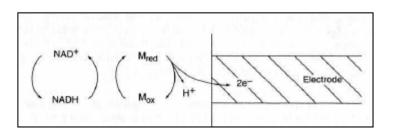
electrode are deliberately changed by placement of a reagent onto the surface

self assembled monolayers

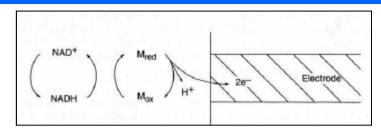
$$RSH + Au \rightleftharpoons RS - Au + e^- + H^+$$

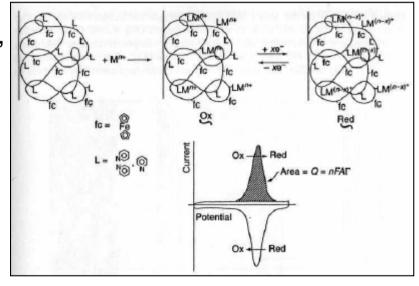
- CNT modified electrodes
- Sol-gel encapsulation of reactive species (3D hydroxilated network is formed for entrapment of a modifier)
- Electrocatalytically modified electrodes (with mediator, e.g. NADH, Co-phtalocyanine etc.)
- Pre-concentrating electrodes



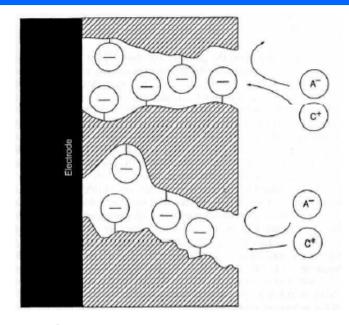


- Chemically modified electrodes:
 - CNT modified electrodes
 - Sol-gel encapsulation of reactive species (3D hydroxilated network is formed for entrapment of a modifier)
 - Electrocatalytically modified electrodes (with mediator, e.g. NADH, Co-phtalocyanine etc.)
 - Pre-concentrating electrodes: collecting analyte via nonelectrolytic step
 - Permselectrive coating: improving selective by allowing transport of analyte while excluding the unwanted species

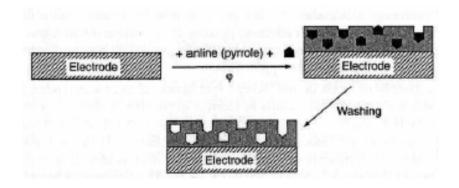




- Chemically modified electrodes:
 - Permselectrive coating: improving selective by allowing transport of analyte while excluding the unwanted species, e.g.
 - via size exclusion
 - via charge exclusion
 - Conducting polymer
 - possibility to switch between conducting and insulating form
 - polymer nanowires
 - molecular imprinted polymers via electropolymerization



Nafion-coated electrode: excluding anionic interference due to negatively charged sulfonated groups in the pores



Microelectrodes

- measurement of in microflow systems,
- analysis of small samples
- in vivo measurements
- possibility to work in highly resistive solutions
- reduced double layer capacitance
- large component of spherical diffusion

